EL - 23G

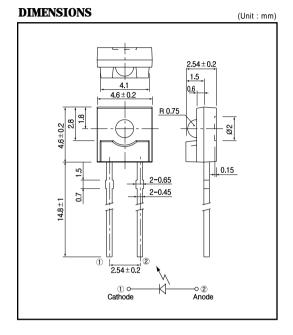
The EL - 23G, a high - power GaAs IRED mounted in a clear sidelooking package, is compact, low profile, and easy to mount.

FEATURES

- Compact
- Low profile package
- Low cost
- · Sidelooking plastic package

APPLICATIONS

- Photointerrupters
- Optical switches
- Toys



MAXIMUM RATINGS

(Ta=25)

Item	Symbol	Rating	Unit
Reverse voltage	VR	5	V
Forward current	 F	60	mA
Pulse forward current *1	 FP	1	Α
Power dissipation	P□	100	mW
Operating temp.	Topr.	- 20~ + 100	
Storage temp.	Tstg.	- 30~ + 100	
Soldering temp. *2	Tsol.	240	

^{*1.} pulse width: tw 100 pec.period: T=10msec.

ELECTRO-OPTICAL CHARACTERISTICS

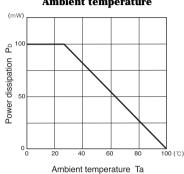
(Ta=25)

Item	Symbol	Conditions	Min.	Тур.	Max.	Unit.
Forward voltage	VF	I==60mA		1.3	1.6	V
Reverse current	I _R	Vr=5V			10	μA
Capacitance	Ct	f=1MHz		25		pF
Radiant intensity	P∘	I==60mA		2.0		mW/sr
Peak emission wavelength	р	I==60mA		940		nm
Spectral bandwidth 50%		l⊧=60mA		50		nm
Half angle				± 30		deg.

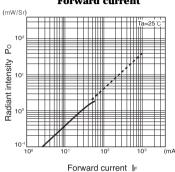
^{*2.} For MAX.5 seconds at the position of 2 mm from the package

EL - 23G

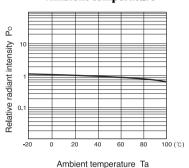
Power dissipation Vs. Ambient temperature



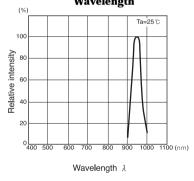
Radiant intensity Vs. Forward current

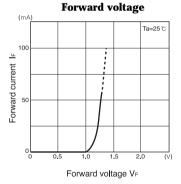


Relative radiant intensity Vs.
Ambient temperature



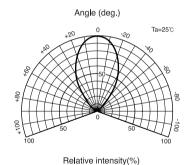
Relative intensity Vs. Wavelength



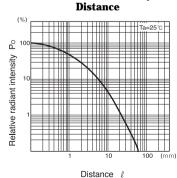


Forward current vs.

Radiant Pattern



Relative radiant intensity Vs.



Relative radiant intensity Vs.
Distance test method

